

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	l⊳ max Tc = +25°C
60V	11mΩ @ V <sub>GS</sub> = 10V	47.6A
00 V	16mΩ @ V <sub>GS</sub> = 4.5V	39.5A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

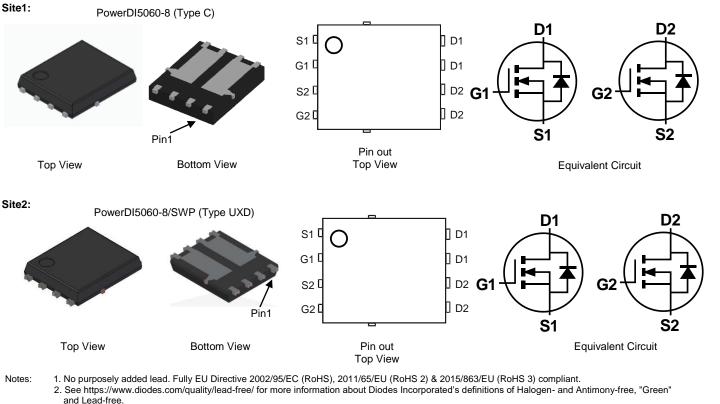
- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

### **Features and Benefits**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/guality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMTH6010LPDQ</u>)

## **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

PowerDI is a registered trademark of Diodes Incorporated.

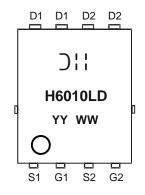


## Ordering Information (Note 4)

Part Number	Deskars	Packing		
Part Number	Package	Qty.	Carrier	
DMTH6010LPD-13	PowerDI5060-8 (Type C)	2,500	Tape & Reel	
DMTH6010LPD-13	PowerDI5060-8/SWP (Type UXD)	2,500	Tape & Reel	

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



);; = Manufacturer's Marking H6010LD = Product Type Marking Code YYWW or YYWW = Date Code Marking YY or  $\overline{YY}$  = Year (ex: 21 = 2021) WW = Week (01 to 53)

## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			Vdss	60	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) $T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$		ID	47.6 33.7	А	
Continuous Drain Current (Note 5)	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	13.1 10.9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	170	A		
Maximum Continuous Body Diode Forward Current (Note 6)			ls	31	А
Avalanche Current, L = 0.1mH			las	20	A
Avalanche Energy, L = 0.1mH			Eas	20	mJ

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	53	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	37.5	W
Thermal Resistance, Junction to Case (Note 6)	·	Rejc	4	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).



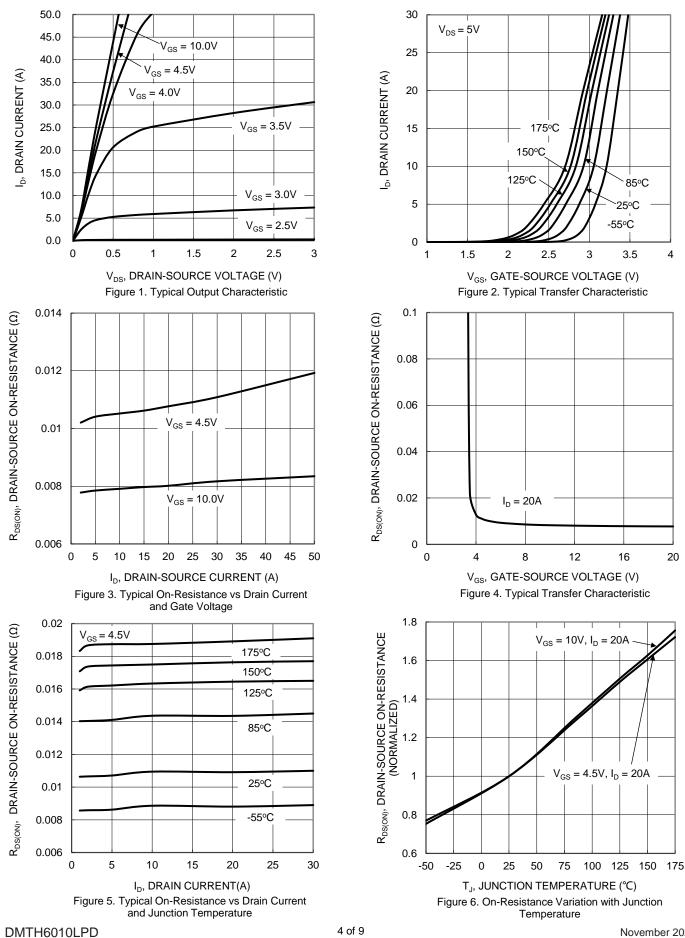
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Turp	Мах	Unit	Test Condition	
	Symbol	WIIN	Тур	wax	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			1	1		<u> </u>	
Drain-Source Breakdown Voltage	BVDSS	60			V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 48V$ , $V_{GS} = 0V$	
Gate-Source Leakage	IGSS	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	1	—	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Deserve	_	8.5	11	mΩ	Vgs = 10V, ID = 20A	
Static Drain-Source On-Resistance	Rds(on)	_	10.9	16	11122	$V_{GS} = 4.5V, I_D = 20A$	
Diode Forward Voltage	Vsd	_	0.9	1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 20A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	2615	_	pF		
Output Capacitance	Coss	—	1415	_	pF	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz	
Reverse Transfer Capacitance	Crss	_	58	—	pF		
Gate Resistance	Rg	_	0.67	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	20.3	—	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	40.2	—	nC		
Gate-Source Charge	Qgs	—	5.9	-	nC	VDS = 30V, ID = 20A	
Gate-Drain Charge	Q <sub>gd</sub>	_	9.3	—	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>		5.7	—	ns		
Turn-On Rise Time	tR		8.8	—	ns	V <sub>DD</sub> = 30V, V <sub>GS</sub> = 10V,	
Turn-Off Delay Time	tD(OFF)	_	20.8	—	ns	$I_D = 20A, R_G = 3\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	_	7.4	—	ns		
Body Diode Reverse Recovery Time	t <sub>RR</sub>	—	34.5	—	ns		
Body Diode Reverse Recovery Charge	Qrr		37.5	—	nC	I⊧ = 20A, di/dt = 100A/µs	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



## DMTH6010LPD

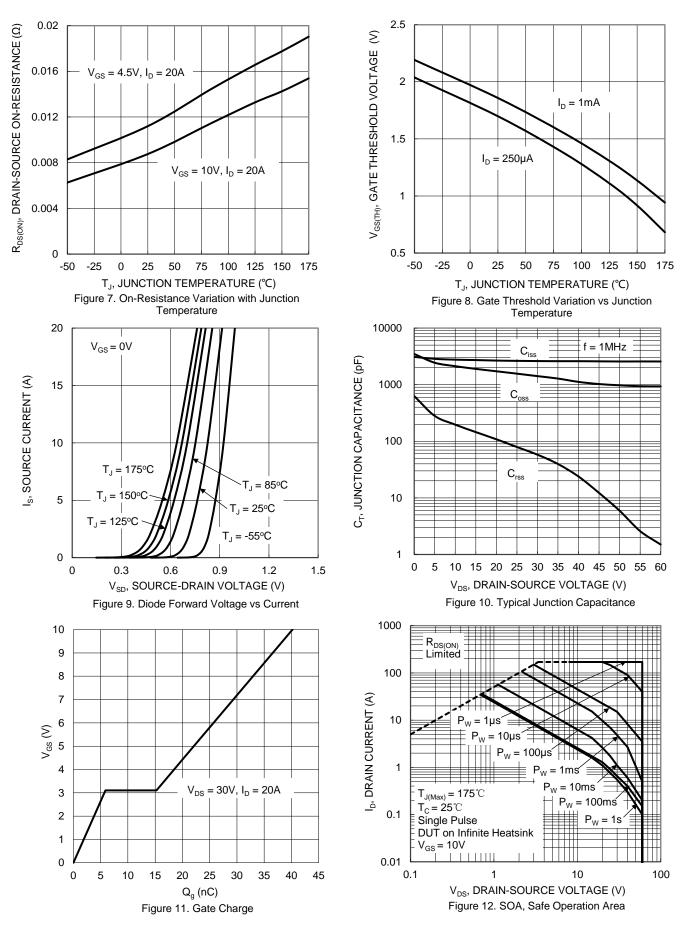


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# DMTH6010LPD



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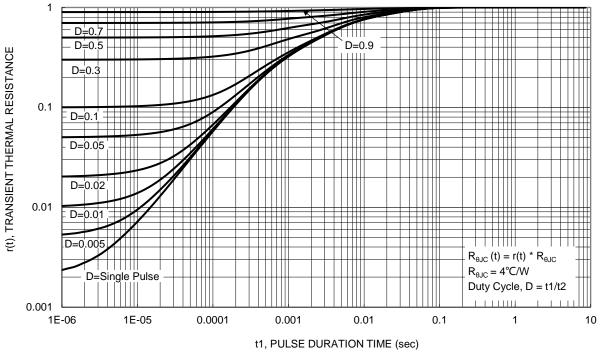


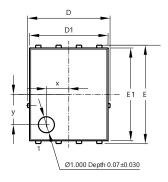
Figure 13. Transient Thermal Resistance

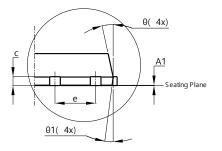


## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version. Site1:

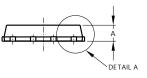
PowerDI5060-8 (Type C)





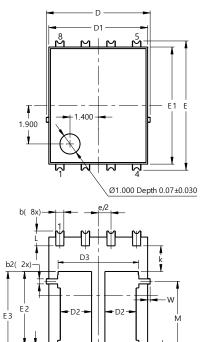
 $\begin{array}{c} \begin{array}{c} \begin{array}{c} b1(8x) \\ e/2 \\ \hline \\ 03 \\ \hline \\ 03 \\ \hline \\ 02 \\ \hline 02$ 

DETAIL A

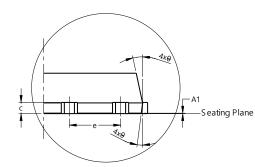


Pov	werDI506	60-8 (Тур	be C)	
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05	0.02	
b	0.33	0.51	0.41	
b1	0.300	0.366	0.333	
b2	0.20	0.35	0.25	
С	0.23	0.33	0.277	
D	į	5.15 BSC	;	
D1	4.85	4.95	4.90	
D2	1.40	1.60	1.50	
D3	-	-	3.98	
Е	(	6.15 BSC	)	
E1	5.75	5.85	5.80	
E2	3.56	3.76	3.66	
е		1.27BSC	;	
k	-	-	1.27	
k1	0.56	-	-	
L	0.51	0.71	0.61	
La	0.51	0.71	0.61	
L1	0.05	0.20	0.175	
L4	-	-	0.125	
М	3.50	3.71	3.605	
х	-	-	1.400	
У	-	-	1.900	
θ	10°	12°	11°	
θ1	6°	8°	7°	
AI	All Dimensions in mm			

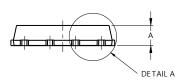
Site2:



PowerDI5060-8/SWP (Type UXD)



DETAIL A



PowerDI5060-8/SWP					
	(Type UXD)				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	(	).25REF	-		
C	0.230	0.330	0.277		
D	5	.15 BS0	2		
D1	4.70	5.10	4.90		
D2	1.46	1.66	1.55		
D3	3.78 4.18 3.98		3.98		
ш	6	.40 BS0	2		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC	)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
М	3.205	4.005	3.605		
W	0.025	0.225	0.125		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	Dimensi	ions in	mm		

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-L1

-b4( 8x)

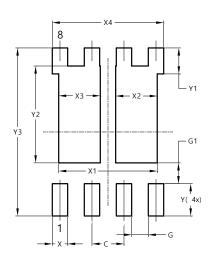


## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site1:

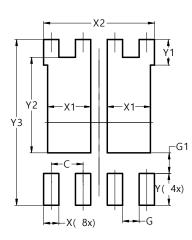
PowerDI5060-8 (Type C)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	3.910		
X2	1.650		
X3	1.650		
X4	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		

Site2:

### PowerDI5060-8/SWP (Type UXD)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	1.720
X2	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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